

FDP75N08A N-Channel UniFET[™] MOSFET 75 V, 75 A, 11 mΩ

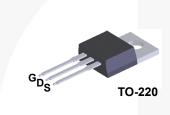
Features

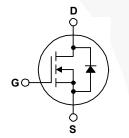
- 75 A, 75 V, $R_{DS(on)}$ = 11 m Ω @ V_{GS} = 10 V Low Gate Charge (Typ. 145 nC)
- Low Crss (Typ. 86 pF)
- · Fast Switching
- Improved dv/dt Capability



Description

UniFET[™] MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.





Absolute Maximum Ratings T_c = 25°C unless otherwise noted.

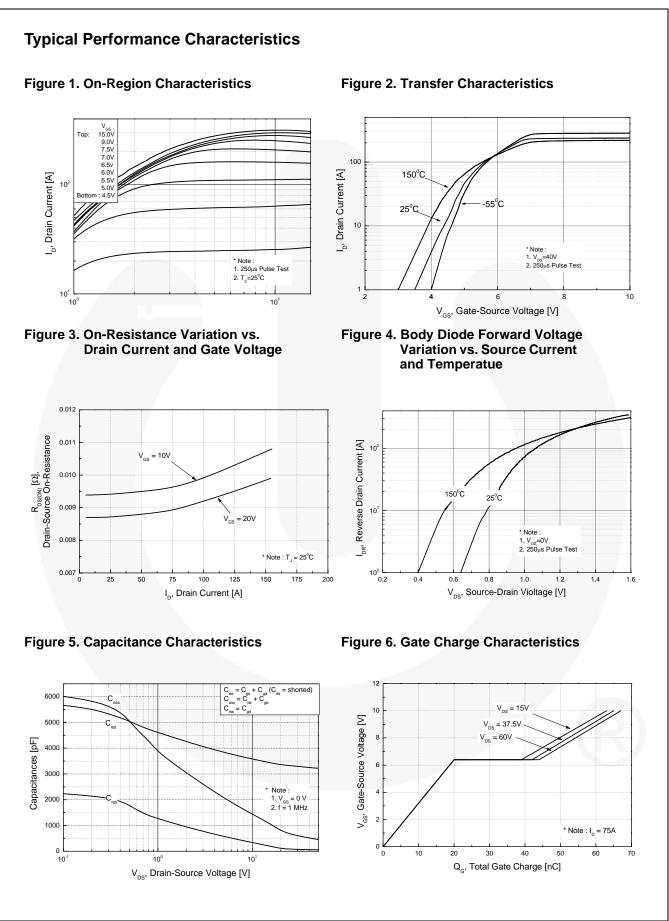
Symbol	Parameter		FDP75N08A	Unit	
V _{DSS}	Drain-Source Voltage		75	V	
I _D	Drain Current - Continuous ($T_C = 25^{\circ}C$)		75	А	
	- Continuous (T _C = 100°C)		47	A	
I _{DM}	Drain Current - Pulsed	(Note 1)	300	A	
V _{GSS}	Gate-Source Voltage		± 20	V	
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	1738	mJ	
I _{AR}	Avalanche Current	(Note 1)	75	A	
E _{AR}	Repetitive Avalanche Energy	(Note 1)	13.7	mJ	
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	4.5	V/ns	
P _D	Power Dissipation ($T_C = 25^{\circ}C$)		137	W	
	- Derate Above 25°C		1.09	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C	
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	°C	

Thermal Characteristics

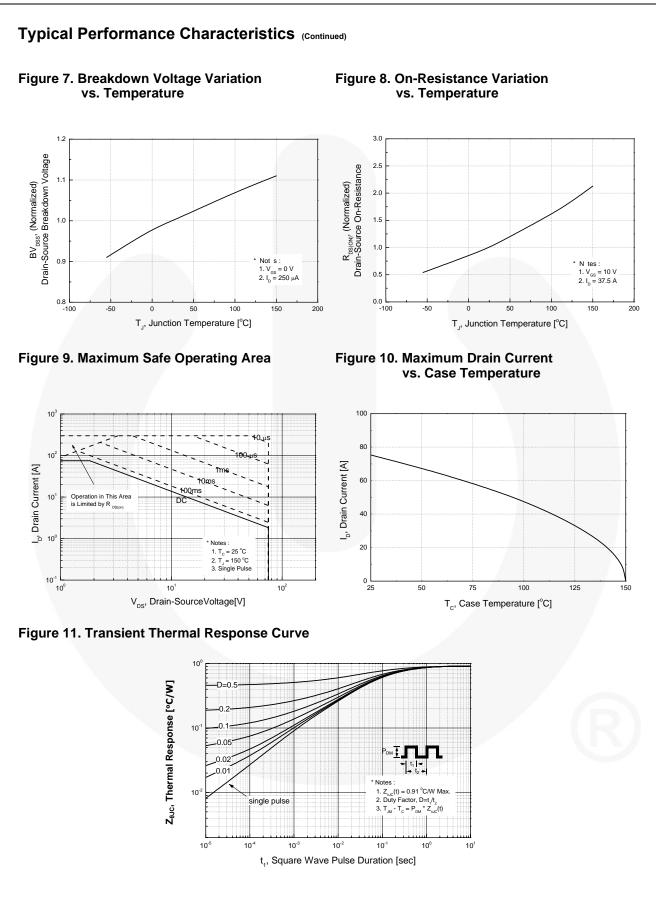
Symbol	Parameter	FDP75N08A	Unit	
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction-to-Case, Max.	0.91	°C/W	
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W	

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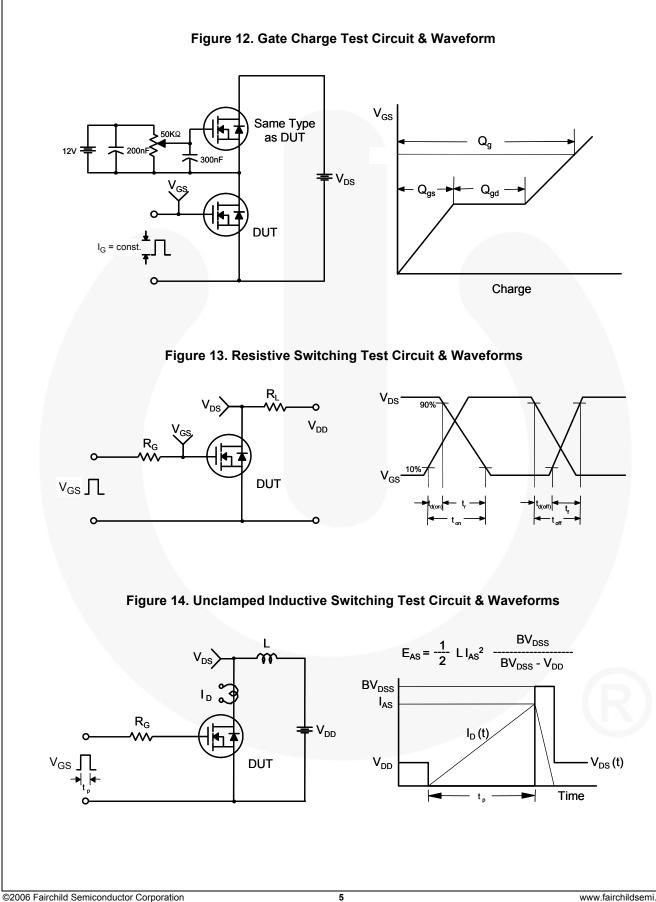
		Device	Packag	ge	Reel Size	Та	pe Widtł	า	Quanti	ity
		TO-22	•			N/A		50 units		
Electric	al Char	acteristics TC =	25°C unless oth	nerwise noted.						
Symbol		Parameter		Test	Conditions	6	Min.	Тур.	Max.	Unit
Off Charac	teristics							1		
BV _{DSS}	Drain-Sou	rce Breakdown Voltage		$V_{GS} = 0 V, I$	_D = 250 μA		75			V
ΔBV_{DSS} / ΔT_{J}	Breakdown Voltage Temperature Coefficient		$I_D = 250 \ \mu$ A, Referenced to 25°C			0.6		V/°C		
I _{DSS} Zero Gate Voltage Drain Curr		Voltage Drain Current		V _{DS} = 75 V,	V _{GS} = 0 V				1	μΑ
				V _{DS} = 60 V, T _C = 125°C				10	μΑ	
I _{GSSF}	Gate-Body	Leakage Current, Forv	ward	$V_{GS} = 20 V,$	$V_{DS} = 0 V$				100	nA
I _{GSSR}	Gate-Body	v Leakage Current, Rev	rerse	V _{GS} = -20 V	, V _{DS} = 0 V				-100	nA
On Charact	eristics									
V _{GS(th)}	Gate Three	shold Voltage		$V_{\rm DS} = V_{\rm GS},$	I _D = 250 μA		2.0		4.0	V
R _{DS(on)}	Static Drain	n-Source On-Resistand	e	$V_{GS} = 10 V,$	I _D = 37.5 A			9.4	11	mΩ
9 _{FS}	Forward T	ransconductance		V _{DS} = 40 V,	I _D = 37.5 A			15		S
Dynamic Cl	naracteristic	s								
C _{iss}	Input Capa	acitance		V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz				3437	4468	pF
C _{oss}	Output Ca	pacitance					-	738	959	pF
C _{rss}	Reverse T	ransfer Capacitance				-	86	129	pF	
Switching C	haracteristi	cs								
t _{d(on)}	Turn-On D	elay Time		V _{DD} = 37.5 V, I _D = 75A,				43	95	ns
t _r	Turn-On R	ise Time		R _G = 25 Ω				212	434	ns
t _{d(off)}	Turn-Off D	elay Time						273	556	ns
t _f	Turn-Off Fa	all Time		-	(Note 4)			147	303	ns
Qg	Total Gate	Charge		$V_{DS} = 60 \text{ V, } I_D = 75\text{A},$ $V_{GS} = 10 \text{ V}$ (Note 4)				80	104	nC
Q _{gs}	Gate-Sour	ce Charge						20		nC
Q _{gd}	Gate-Drain	n Charge				(Note 4)		24	7	nC
Drain-Sourc	e Diode Ch	aracteristics and Maxin	num Ratings					I		
I _S	Maximum	Continuous Drain-Sour	ce Diode Fo	orward Current					75	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forwar		iode Forwar	rd Current				300	Α	
V _{SD}	Drain-Sour	rce Diode Forward Volt	age	V _{GS} = 0 V, I _S = 75 A					1.4	V
t _{rr}	Reverse R	ecovery Time		V _{GS} = 0 V, I				62		ns
Q _{rr}	Reverse R	ecovery Charge		dl _F / dt = 100 A/μs				145		nC

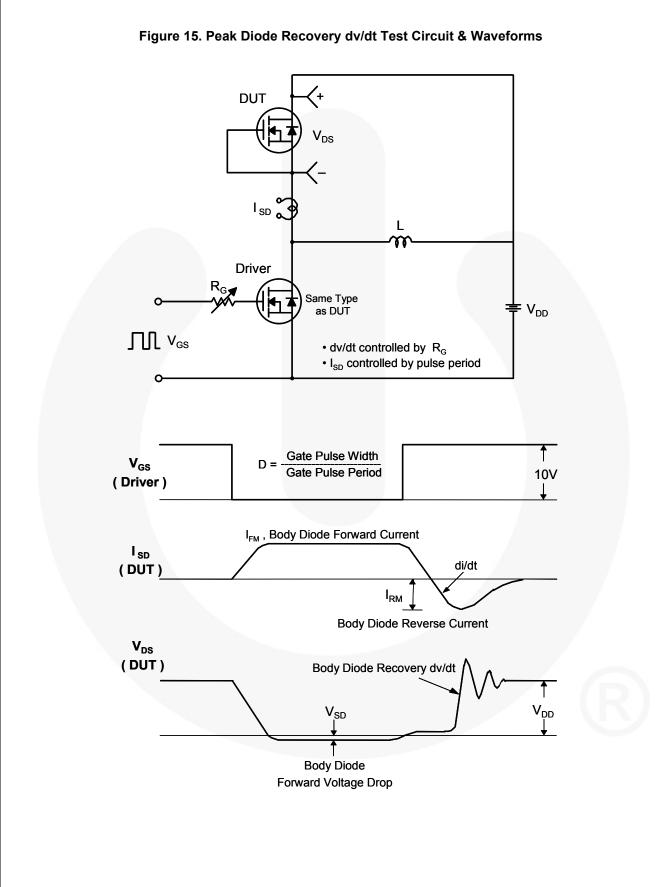


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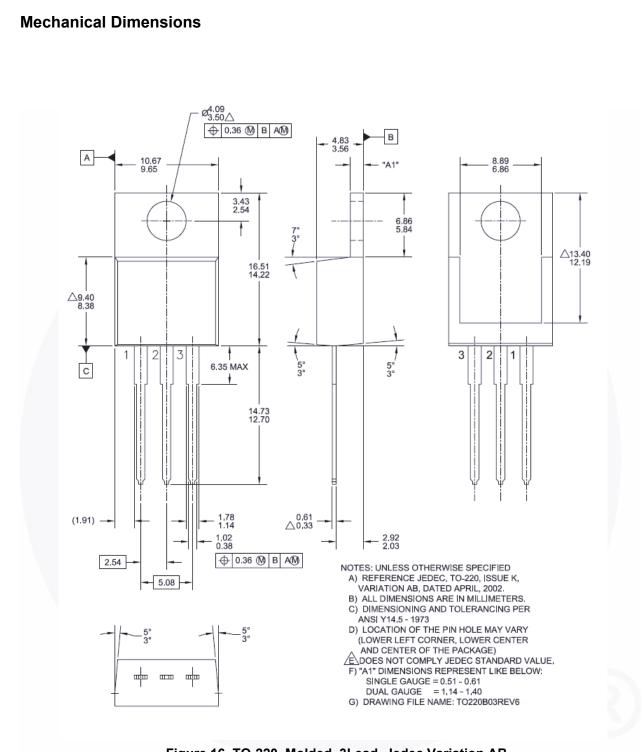


Figure 16. TO-220, Molded, 3Lead, Jedec Variation AB

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